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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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# SANYO Semiconductors DATA SHEET

# SBT80-10JS — Schottky Barrier Diode (Twin Type · Cathode Common) 100V, 8A Rectifier

### **Applications**

· High frequency rectification (switching regulators, converters, choppers).

#### **Features**

- Tj=150°C.
- Low forward voltage (VF max=0.80V).
- · Short reverse recovery time.
- · Low switching noise.
- · High reliability due to highly reliable planar structure.
- · Micaless package facilitating mounting.

### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>		100	٧
Nonrepetitive Peak Reverse Surge Voltage	V <sub>RSM</sub>		105	V
Average Output Current	lo	50Hz resistive load, Sine wave Tc=81°C	8	Α
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	60	Α
Junction Temperature	Tj		-55 to +150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

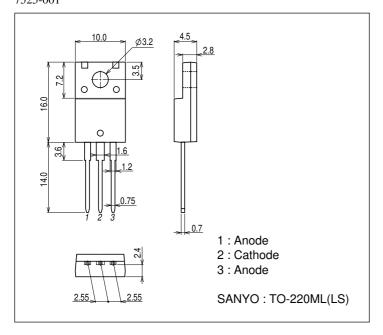
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Reverse Voltage	VR	I <sub>R</sub> =1mA, Tj=25°C*	100			V
Forward Voltage	VF	IF=3.0A, Tj=25°C*			0.80	٧
Reverse Current	IR	V <sub>R</sub> =50V, Tj=25°C*			0.1	mA
Interterminal Capacitance	С	V <sub>R</sub> =10V, Tj=25°C*		90		pF
Thermal Resistance	Rth(j-c)	Junction-Case : Smoothed DC			5.0	°C / W

Note) \* : Value per element

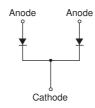
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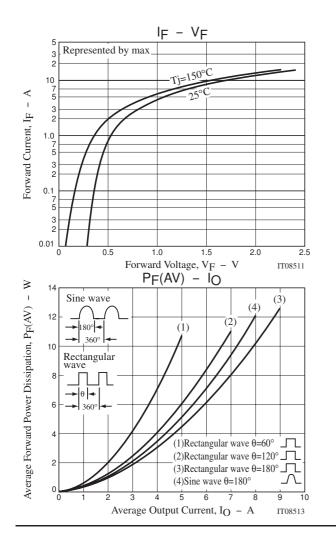
#### **Package Dimensions**

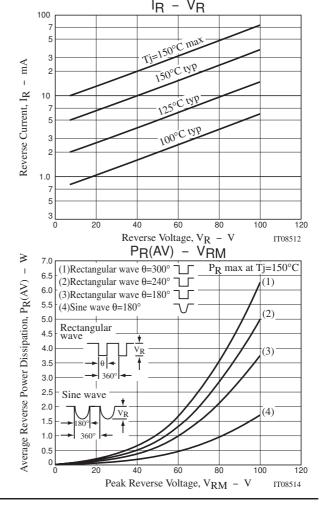
unit : mm (typ) 7525-001



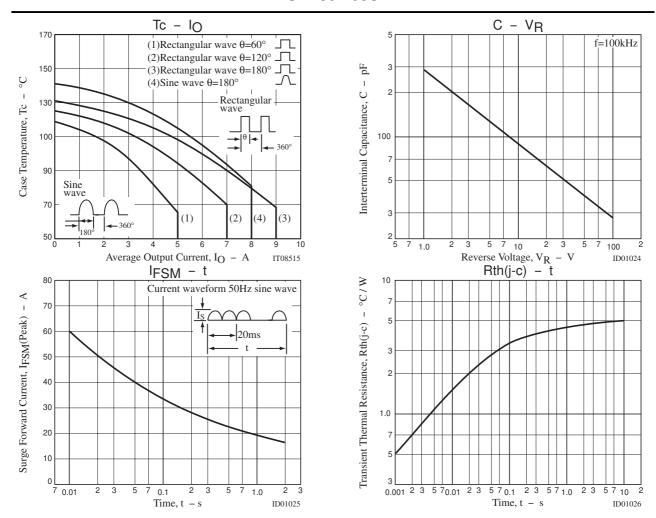
## **Electrical Connection**







#### **SBT80-10JS**



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